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TLC6C598-Q1

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TLC6C598-Q1 Power Logic 8-Bit Shift Register LED Driver

Technical

Documents

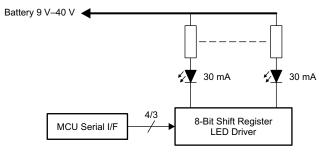
1 Features

- Qualified for Automotive Applications
- AEC-Q100 Qualified With the Following Results:
 - Device Temperature Grade 1: -40°C to 125°C Ambient Operating Temperature Range
 - Device HBM ESD Classification Level H2
 - Device CDM ESD Classification Level C3B
- Wide Vcc From 3 V to 5.5 V
- Output Maximum Rating of 40 V
- Eight Power DMOS Transistor Outputs of 50-mA Continuous Current With $V_{CC} = 5 V$
- **Thermal Shutdown Protection**
- Enhanced Cascading for Multiple Stages
- All Registers Cleared With Single Input
- Low Power Consumption
- Slow Switching Time (t, and t), Which Helps Significantly With Reducing EMI
- 16-Pin TSSOP-PW Package
- 16-Pin SOIC-D Package •

2 Applications

- Instrumentation Cluster
- **Tell-Tale Lamps**
- LED Illumination and Control

Typical Application Schematic



3 Description

Tools &

Software

The TLC6C598-Q1 is a monolithic, medium-voltage, low-current power 8-bit shift register designed for use in systems that require relatively moderate load power, such as LEDs.

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This device contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. Data transfers through both the shift and storage registers on the rising edge of the shiftregister clock (SRCK) and the register clock (RCK), respectively. The storage register transfers data to the output buffer when shift register clear (\overline{CLR}) is high. A low on CLR clears all registers in the device. Holding the output enable (\overline{G}) high, holds all data in the output buffers low, and all drain outputs are off. Holding \overline{G} low makes data from the storage register transparent to the output buffers. When data in the output buffers is low, the DMOS transistor outputs are off. When data is high, the DMOS transistor outputs have sink-current capability. The serial output (SER OUT) clocks out of the device on the falling edge of SRCK to provide additional hold time for cascaded applications. This provides improved performance for applications where clock signals may be skewed, devices are not located near one another, or the system must tolerate electromagnetic interference. The device contains built-in thermal shutdown protection.

Outputs are low-side, open-drain DMOS transistors with output ratings of 40 V and 50 mA continuous sink-current capabilities when Vcc = 5 V. The current limit decreases as the junction temperature increases for additional device protection. The device also provides up to 2000 V of ESD protection when tested using the human-body model and 200 V when using the machine model.

The TLC6C598-Q1 characterization is for for operation over the operating ambient temperature range of -40°C to 125°C.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
TLC6C598-Q1	SOIC (16)	9.90 mm x 3.91 mm		
	TSSOP (16)	5.00 mm x 4.40 mm		

(1) For all available packages, see the orderable addendum at the end of the datasheet.



Product Folder Links: TLC6C598-Q1

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	nanges from Revision C (October 2015) to Revision D P	age
•	Added Receiving Notification of Documentation Updates section	. 17
•	Added new orderable part number to Package Option Addendum	. 18

Changes from Revision B (March 2013) to Revision C

 Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section

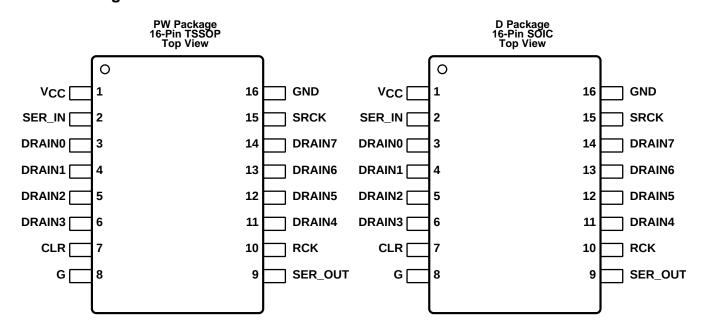
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Page



5 Pin Configuration and Functions



Pin Functions

PIN		- I/O	DESCRIPTION		
NAME	NO.	1/0	DESCRIPTION		
CLR	7	I	Shift register clear, active-low. The storage register transfers data to the output buffer when CLR is high. Driving CLR low clears all the registers in the device.		
DRAIN0	3	0	Open-drain output, LED current-sink channel, connect to LED cathode		
DRAIN1	4	0	Open-drain output, LED current-sink channel, connect to LED cathode		
DRAIN2	5	0	Open-drain output, LED current-sink channel, connect to LED cathode		
DRAIN3	6	0	Open-drain output, LED current-sink channel, connect to LED cathode		
DRAIN4	11	0	Open-drain output, LED current-sink channel, connect to LED cathode		
DRAIN5	12	0	Open-drain output, LED current-sink channel, connect to LED cathode		
DRAIN6	13	0	Open-drain output, LED current-sink channel, connect to LED cathode		
DRAIN7	14	0	Open-drain output, LED current-sink channel, connect to LED cathode		
G	8	I	Open-drain output, LED current-sink channel, connect to LED canode Output enable, active-low. LED-channel enable and disable input pin. Having G low enables all drain channels according to the output-latch register content. When high, all channels are off.		
GND	16	_	Power ground, the ground reference pin for the device. This pin must connect to the ground plane on the PCB.		
RCK	10	I	Register clock. The data in each shift register stage transfers to the storage register at the rising edge of RCK.		
SER IN	2	I	Serial data input. Data on SER IN loads into the internal register on each rising edge of SRCK.		
SER OUT	9	0	Serial data output of the 8-bit serial shift register. The purpose of this pin is to cascade several devices on the serial bus.		
SRCK	15	I	Serial clock input. On each rising SRCK edge, data transfers from SER IN to the internal serial shift registers.		
V _{CC}	1	I	Power supply pin for the device. TI recommends adding a 0.1- μ F ceramic capacitor close to the pin.		

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Logic supply voltage	-0.3	8	V
VI	Logic input-voltage range	-0.3	8	V
V _{DS}	Power DMOS drain-to-source voltage	-0.3	42	V
	Continuous total dissipation	See Thermal	See Thermal Information	
T _A	Operating ambient temperature	-40	125	°C
TJ	Operating junction temperature range	-40	150	°C
T _{stg}	Storage temperature range	-55	165	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

				VALUE	UNIT
		Human body model (HBM), per AEC Q100	D-002 ⁽¹⁾	±2000	
V _(ESD) Electrostatic discharge	Charged device model (CDM), per AEC	All pins	±750	V	
(ESD)		Q100-011	Corner pins (1, 8, 9, and 16)	±750	•

(1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

		MIN	MAX	UNIT
V _{CC}	Supply voltage	3	5.5	V
VIH	High-level input voltage	2.4		V
VIL	Low-level input voltage		0.7	V
T _A	Operating ambient temperature	-40	125	°C

6.4 Thermal Information

		TLC6C5	TLC6C598-Q1		
	THERMAL METRIC ⁽¹⁾	PW (TSSOP)	D (SOIC)	UNIT	
		16 PINS	16 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	129.4	100	°C/W	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	55.4	45	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	65.8	40	°C/W	
ΨJT	Junction-to-top characterization parameter	9.9	10	°C/W	
Ψјв	Junction-to-board characterization parameter	65.2	40	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	NA	NA	°C/W	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).

6.5 Electrical Characteristics

 V_{CC} = 5 V, T_{C} = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDIT	TIONS	MIN	TYP	MAX	UNIT
	DRAIN0 to DRAIN7. Drain-to- source voltage					40	V
V	High-level output voltage, SER	I _{OH} = -20 μA		4.9	4.99		V
V _{OH}	OUT	$I_{OH} = -4 \text{ mA}$	$v_{CC} = 5 v$	4.5	4.69		V
V _{OL}	Low-level output voltage, SER	I _{OH} = 20 μA			0.001	0.01	V
VOL	OUT	I _{OH} = 4 mA	$v_{CC} = 2 v$		0.25	0.4	V
I _{IH}	High-level input current	V_{CC} = 5 V, V_{I} = V_{CC}			0.2		μA
IIL	Low-level input current	$V_{CC} = 5 V, V_I = 0$			-0.2		μA
1	Logic supply current	$V_{CC} = 5 V$, no clock signal	All outputs off		0.1	1	μA
I _{CC}	Logic supply current	$v_{\rm CC} = 5 v$, no clock signal	All outputs on		88	160	μА
I _{CC(FRQ)}	Logic supply current at frequency	f_{SRCK} = 5 MHz, C_L = 30 pF	All outputs on		200		μA
1	Off-state drain current	V _{DS} = 30 V	$V_{CC} = 5 V$			0.1	μA
I _{DSX}		$V_{DS} = 30 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$	$V_{CC} = 5 V$		0.15	0.3	μА
	Static drain-source on-state resistance	$I_D = 20$ mA, $V_{CC} = 5$ V, $T_A = 2$ Single channel ON	5°C,	6	7.41	8.6	
		$I_D = 20 \text{ mA}, V_{CC} = 5 \text{ V}, T_A = 2 \text{ All channels ON}$	5°C,	6.7	8.3	9.6	
		$I_D = 20 \text{ mA}, V_{CC} = 3.3 \text{ V}, T_A = $ Single channel ON	25°C,	7.9	9.34	11.2	
_		$I_D = 20 \text{ mA}, V_{CC} = 3.3 \text{ V}, T_A = All channels ON$	25°C,	8.7	10.25	12.3	0
r _{DS(on)}		$I_D = 20$ mA, $V_{CC} = 5$ V, $T_A = 1$ Single channel ON	25°C,	9.1	11.13	12.9	Ω
		$I_D = 20 \text{ mA}, V_{CC} = 5 \text{ V}, T_A = 1$ All channels ON	25°C,	10.3	12.28	14.5	
		I_D = 20 mA, V_{CC} = 3.3 V, T_A = Single channel ON	: 125°C,	11.6	13.69	16.4	
		I_D = 20 mA, V_{CC} = 3.3 V, T_A = All channels ON	: 125°C,	12.8	14.89	18.2	
T _{SHUTDOWN}	Thermal shutdown trip point			150	175	200	٥C
T _{hys}	Hysteresis				15		٥C

6.6 Timing Requirements

		MIN	NOM MAX	UNIT
t _{su}	Setup time, SER IN high before SRCK [↑]	15		ns
t _h	Hold time, SER IN high after SRCK↑	15		ns
tw	SER IN pulse duration	40		ns

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6.7 Switching Characteristics

 $V_{CC} = 5 V, T_{J} = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	MIN TY	P MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output from \overline{G}		22	C	ns
t _{PHL}	Propagation delay time, high-to-low-level output from \overline{G}	C = 30 pE = 48 m	7	5	ns
t _r	Rise time, drain output	C _L = 30 pF, I _D = 48 mA	21	D	ns
t _f	Fall time, drain output		12	В	ns
t _{pd}	Propagation delay time, SRCK↓ to SER OUT	$C_{L} = 30 \text{ pF}, I_{D} = 48 \text{ mA}$	49.	4	ns
t _{or}	SER OUT rise time (10% to 90%)	C _L = 30 pF	2	C	ns
t _{of}	SER OUT fall time (90% to 10%)	C _L = 30 pF	2	D	ns
f _(SRCK)	Serial clock frequency	$C_{L} = 30 \text{ pF}, I_{D} = 20 \text{ mA}$		10	MHz
t _{SRCK_WH}	SRCK pulse duration, high		30		ns
t _{SRCK_WL}	SRCK pulse duration, low		30		ns



6.8 Timing Waveforms

Figure 1 shows the SER IN to SER OUT waveform. The output signal appears on the falling edge of the shift register clock (SRCK) because there is a phase inverter at SER OUT (see Figure 13). As a result, it takes seven and a half periods of SRCK for data to transfer from SER IN to SER OUT.

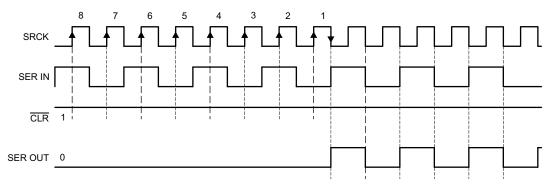
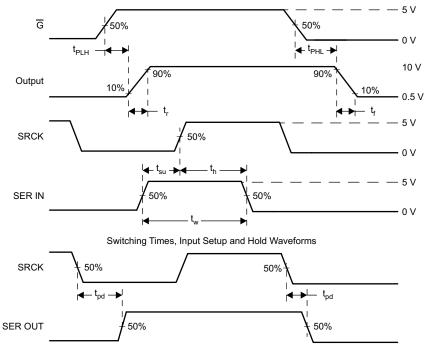




Figure 2 shows the switching times and voltage waveforms. Tests for all these parameters took place using the test circuit shown in Figure 11.



SER OUT Propagation Delay Waveform

Figure 2. Switching Times and Voltage Waveforms

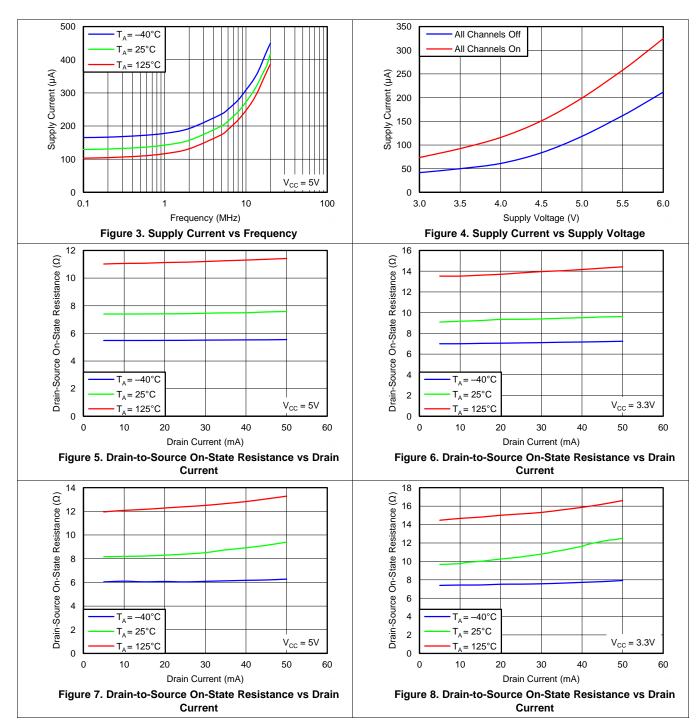
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6.9 Typical Characteristics

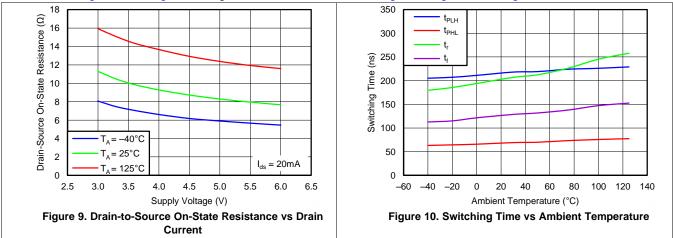
Conditions for Figure 5 and Figure 6: Single channel on, conditions for Figure 7, Figure 8 and Figure 9: All channels on





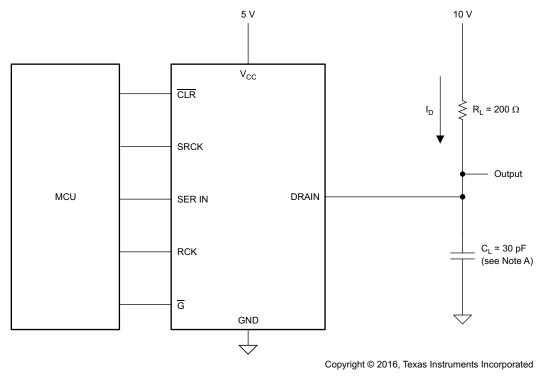
Typical Characteristics (continued)

Conditions for Figure 5 and Figure 6: Single channel on, conditions for Figure 7, Figure 8 and Figure 9: All channels on



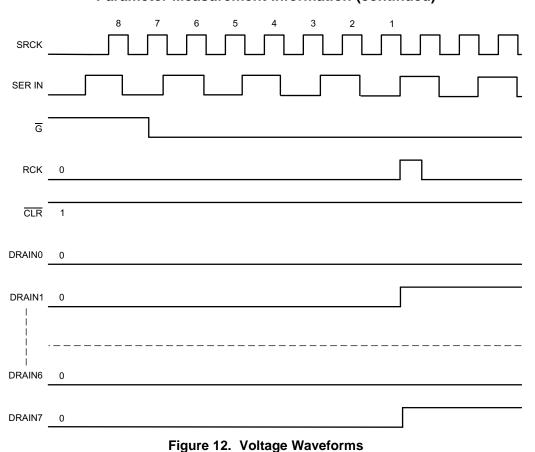
7 Parameter Measurement Information

Figure 11 and Figure 12 show the resistive-load test circuit and voltage waveforms. One can see from Figure 12 that with G held low and CLR held high, the status of each drain changes on the rising edge of the register clock, indicating the transfer of data to the output buffers at that time.



A. C_L includes probe and jig capacitance.





Parameter Measurement Information (continued)





8 Detailed Description

8.1 Overview

The TLC6C598-Q1 device is a monolithic, medium-voltage, low-current 8-bit shift register designed to drive relatively moderate load power such LEDs. The device contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. Thermal shutdown protection is also built-into the device.

8.2 Functional Block Diagram

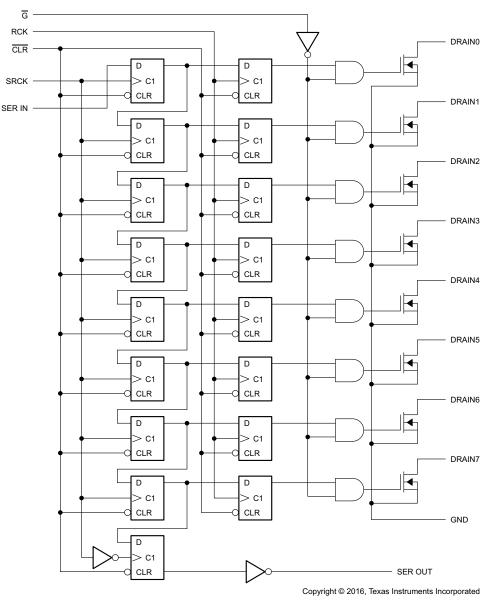


Figure 13. Logic Diagram (Positive) of TLC6C598-Q1



8.3 Feature Description

8.3.1 Thermal Shutdown

The device implements an internal thermal shutdown to protect itself if the junction temperature exceeds 175°C (typical). The thermal shutdown forces the device to have an open state when the junction temperature exceeds the thermal trip threshold. Once the junction temperature decreases below 160°C (typical), the device begins to operate again.

8.3.2 Serial-In Interface

The TLC6C598-Q1 device contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. Data transfer through the shift and storage registers is on the rising edge of the shift register clock (SRCK) and the register clock (RCK), respectively. The storage register transfers data to the output buffer when shift register clear (CLR) is high.

8.3.3 Clear Registers

A logic low the CLR pin clears all registers in the device. TI suggests clearing the device during power up or initialization.

8.3.4 Output Channels

DRAIN0–DRAIN7. These pins can survive up to 40-V LED supply voltage. This is quite helpful during automotive load-dump conditions.

8.3.5 Register Clock

RCK is the storage-register clock. Data in the storage register appears at the output whenever the output enable (\overline{G}) input signal is high.

8.3.6 Cascade Through SER OUT

By connecting the SER OUT pin to the SER IN input of the next device on the serial bus to cascade, the data transfers to the next device on the falling edge of SRCK. This can improve the cascade application reliability, as it can avoid the issue that the second device receives SRCK and data input at the same rising edge of SRCK.

8.3.7 Output Control

Holding the output enable (pin G) high holds all data in the output buffers low, and all drain outputs are off. Holding G low makes data from the storage register transparent to the output buffers. When data in the output buffers is low, the DMOS transistor outputs are off. When data is high, the DMOS transistor outputs are capable of sinking current. This pin also can be used for global PWM dimming.

8.4 Device Functional Modes

8.4.1 Operation With $V_{CC} < 3 V$

This device works normally within the range 3 V \leq V_{CC} \leq 5.5 V. When the operating voltage is lower than 3 V, correct behavior of the device, including communication interface and current capability, is not assured.

8.4.2 Operation With 5.5 V \leq V_{CC} \leq 8 V

The device works normally in this voltage range, but reliability issues may occur if the device works for a long time in this voltage range.



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TLC6C598-Q1 device is a serial-in, parallel-out, power and logic, 8-bit shift register with low-side open-drain DMOS output ratings of 40-V and 50-mA continuous sink-current capabilities when $V_{CC} = 5$ V. The device is designed to drive resistive loads and is particularly well-suited as an interface between a microcontroller and LEDs or lamps. The device also provides up to 2000 V of ESD protection when tested using the human body model and 200 V when using the machine model

9.2 Typical Application

Figure 14 shows a typical cascade application circuit with two TLC6C598-Q1 chips configured in cascade topology. The MCU generates all the input signals.

TLC6C598-Q1

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Typical Application (continued)

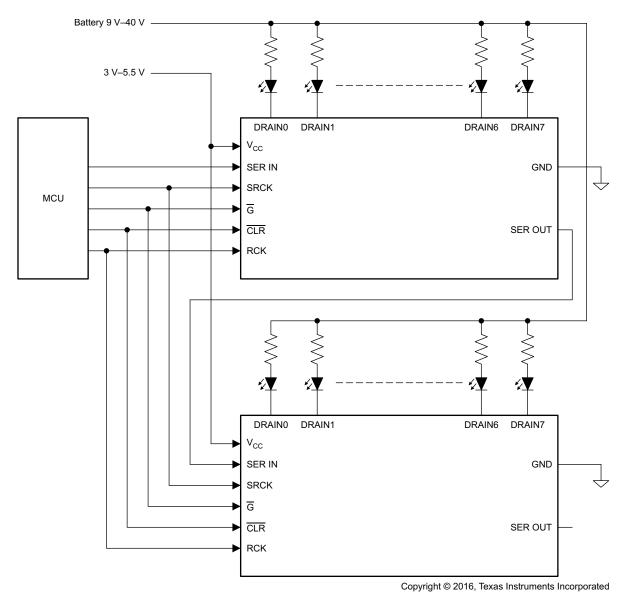


Figure 14. Typical Application Circuit

9.2.1 Design Requirements

DESIGN PARAMETER	EXAMPLE VALUE				
V _{Battery}	9 V to 40 V				
V _{CC_1}	3.3 V				
I(D0), I(D1), I(D2), I(D3) , I(D4), I(D5), I(D6), I(D7)	30 mA				
V _{CC_2}	5 V				
I(D8), I(D9), I(D10), I(D11) , I(D12), I(D13), I(D14), I(D15)	50 mA				



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9.2.2 Detailed Design Procedure

To begin the design process, the designer must decide on a few parameters, as follows:

- V_{supply}: LED supply voltage
- V_{Dx}: LED forward voltage
- I: LED current

With these parameters determined, the resistor in series with the LED can be calculated by using the following equation:

$$R_{X} = (V_{Supply} - V_{Dx}) / I$$

(1)

9.2.3 Application Curve

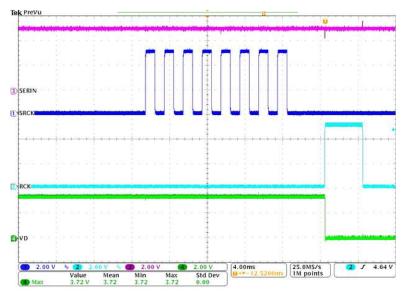


Figure 15. TLC6C598-Q1 Application Waveform



10 Power Supply Recommendations

The TLC6C598-Q1 device is designed to operate with an input voltage supply range from 3 V to 5.5 V. This input supply should be well regulated. TI recommends placing the ceramic bypass capacitors near the V_{CC} pin.

11 Layout

11.1 Layout Guidelines

There are no special layout requirement for the digital signal pins. The only requirement is placing the ceramic bypass capacitors near the corresponding pin.

Maximize the copper coverage on the PCB to increase the thermal conductivity of the board. The major heat-flow path from the package to the ambient is through the cooper on the PCB. Maximizing the copper coverage is extremely important when the design does not include heat sinks attached to the PCB on the other side of the package.

Add as many thermal vias as possible directly under the package ground pad to optimize the thermal conductivity of the board.

All thermal vias should be either plated shut or plugged and capped on both sides of the board to prevent solder voids. To ensure reliability and performance, the solder coverage should be at least 85%.

11.2 Layout Example

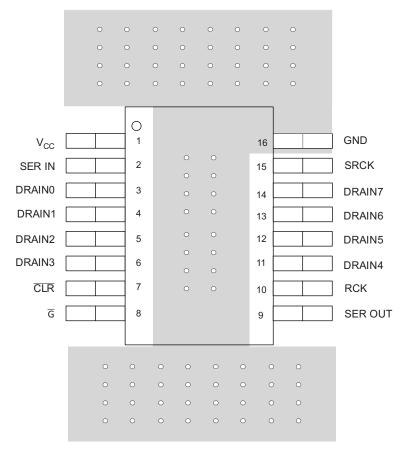


Figure 16. TLC6C598-Q1 Example Layout



12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

13.1 Package Option Addendum

13.1.1 Packaging Information

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish ⁽³⁾	MSL Peak Temp (4)	Op Temp (°C)	Device Marking ⁽⁵⁾⁽⁶⁾
TLC6C598QPWRQ1	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 125	6C598
TLC6C598QDRQ1	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 125	TLC6C598
TLC6C598CQDRQ1	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 125	TLC6C598C

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PRE_PROD Unannounced device, not in production, not available for mass market, nor on the web, samples not available.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

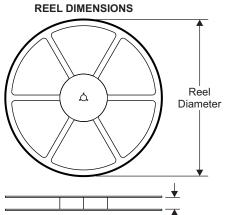
- (3) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.
- (4) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (5) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device
- (6) Multiple Device markings will be inside parentheses. Only on Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

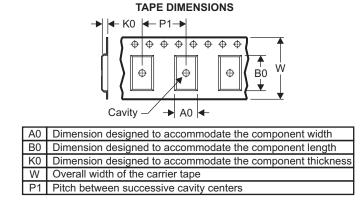
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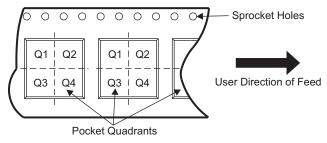
13.1.2 Tape and Reel Information





Reel Width (W1)

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

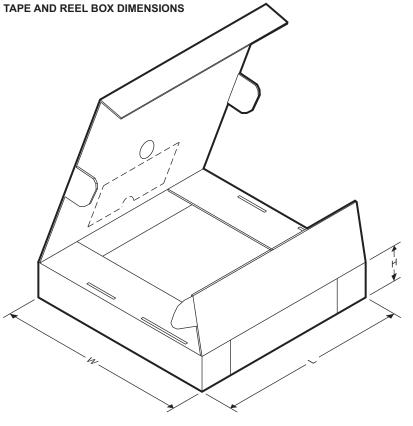


Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC6C598QPWRQ1	TSSOP	PW	16	2000	330	12.4	6.9	5.6	1.6	8	12	Q1
TLC6C598QDRQ1	SOIC	D	16	2500	330	16.4	6.5	10.3	2.1	8	16	Q1
TLC6C598CQDRQ1	SOIC	D	16	2500	330	16.4	6.5	10.3	2.1	8	16	Q1

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC6C598QPWRQ1	TSSOP	PW	16	2000	367	367	38
TLC6C598QDRQ1	SOIC	D	16	2500	367	367	38
TLC6C598CQDRQ1	SOIC	D	16	2500	367	367	38

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



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